





SPF MIT3 02 Plastic Fiber Optic Transmitter including Bigfoot[™] IC for MOST[®]

Preliminary Data Sheet

Safety Hints:

Applications of new chip technologies leads to increasing optical efficiency and growing and higher levels of optical performance. We therefore recommend that the current versions of the IEC 825-1 and EN 60825-1 standards are taken into account right from the outset, i.e. at the equipment development stage, and that suitable protection facilities are provided.

The data sheet of the 4-pin MOST Optical Transmitter (MIT3 02) has to be taken as preliminary. Samples which are delivered before the qualification and the production release are engineering samples.

50Mbaud.

LED.

Description

The MOST BigfootTx Plastic Fiber Optic Transmitter

is a highly integrated CMOS IC combined with a High

speed LED designed to transmit up to 25Mbit/sec

optical data which is biphase coded at up to

The current through the LED will be setup by an

external resistor connected to VCC. This makes it

possible to control the optical output power of the

The internal peaking circuit minimizes PWD.

Features

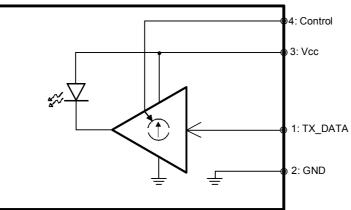
Excellent solution for converting high speed data from TTL to Plastic Optical Fiber (POF)

- High speed transmitter up to 50 Mbaud
- TTL Data Input (Logic to Light Function)
- 650 nm for working in a low attenuation range of PMMA Fiber
- High coupled power in1000 micron plastic fiber
- Low cost

Applications

• Optical Transmitter for MOST Systems





Actual design status:

Bigfoot IC Revision	package type	device marking	Data sheet is valid since
J	CAI	date code,	15-Jan-03
		MIT3 02	



Maximum Ratings

Parameter	Symbol	Min	Мах	Unit
Storage Temperature Range	T _{STG}	-40	100	°C
Junction Temperature	T	-40	100	°C
Soldering Temperature (>2.5 mm from case bottom t≤5s)	T _s	-	235	°C
Power Dissipation	P _{TOT}	-	300	mW
Power Supply Voltage	V _{CCMax}	-0.5	6.0	V

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V _{cc}	4.75	5.25	V
Operating Temperature Range	T _A	-40	85	۵°C
(R _{ext} =13.5 kOhm)				

All the data in this specification refers to the operating conditions above unless otherwise stated.

Optical Signal Characteristics

(22.5 Mbit/s MOST Data, Vcc=4.75 .. 5.25 V)

Parameter	Symbol	Min	Тур	Max	Unit
Peak wavelength at T _A =25°C	λ Peak25	640	650	660	nm
Temperature coefficient λ_{Peak}	ΤCλ	-	0.16	-	nm/K
Peak wavelength at T _A =-4085°C	λ_{Peak}	630	650	670	nm
Spectral bandwidth (FWHM)	Delta λ	-	20	30	nm
Average Output Power coupled into plastic fiber at $T_A=25^{\circ}$ C, $R_{ext}=15$ kOhm, see Note 1	P _{opt25, O}	-7.4 (185)	-5.2 (300)	-3.6 (435)	dBm (µW)
Temperature coefficient Popt	TC _{Popt}	-	- 0.4	-	%/K
Average Output Power coupled into plastic fiber at T_A =-4085°C, R_{ext} =15 kOhm, see Note 1	P _{opt}	-8.6 (140)	-5.2 (300)	-3.1 (490)	dBm (µW)
Average Output Power coupled into plastic fiber at T_A =-4085°C, R_{ext} =15 kOhm, over lifetime, see Note 1	P _{opt, lifetime}	-9.6 (110)	-5.2 (300)	-2.1 (615)	dBm (µW)
Gain in P _{opt} when using 13.5 KOhm instead of 15 KOhm		0.35	0.4	0.45	dB
Optical Rise Time (20% - 80%)	t _r	-	4	6	ns
Optical Fall Time (20% - 80%)	t _f	-	4	6	ns
Extinction Ratio	r _e	10	11	-	dB
Pulse Width Variation, see Note 2	t _{PWV}	20.9	-	24.4	ns
Average Pulse Width Distortion, see Note 2	t _{APWD}	-0.5	-	1.5	ns

Note 1: The output power coupled into plastic fiber P_{opt} is measured with a large area detector at the end of a short length of a fiber (about 30 cm), which is ideally coupled to the Sidelooker. This value must not be used for calculating the power budget for a fiber optic system with a long fiber because the numerical aperture of plastic fibers decreases on the first meters.

Therefore the fiber seems to have a higher attenuation over the first few meters compared with the specified value.

Due to the direct coupling of the fiber to the LED at the end of the short fiber UMD (uniform mode distribution) will be observed. Therefore the following section of the cable has higher losses compared with EMD (equilibrium mode distribution).

Note 2: The electrical input signal fulfills $t_{PWV(min)} = 22.9$ ns and $t_{PWV(max)} = 24.1$ ns. For further details see page 3.





Pulse Width Variation (t_{PWV}) and Average Pulse Width Distortion (t_{APWD})

The SPF MIT3 02 generates negative Puls Width Distortion. This means the optical output signal is shortened compared to the electrical input signal. Therefore the parameters t_{PWV} and t_{APWD} do not meet the MOST Specification of Physical Layer Rev 1.0 (MOST SPL Rev. 1.0) either at the electrical input signal (SP1 in the MOST SPL Rev. 1.0) or at the optical output signal (SP2 in the MOST SPL Rev. 1.0). This characteristic is shown in the following table.

	Parameter	Symbol	Min	Max	Min	Мах	Unit	Remarks
			Electrical Input Signal		Optical Output Signal			
а	Pulse Width Variation	t _{PWV}	22.9	24.1	20.9	24.4	ns	Optical Output Signal according to MOST
	Average Pulse Width Distortion	t _{APWD}	1.0	1.5	-0.5	1.5	ns	Specification of Physical Layer Rev. 1.0
b	Pulse Width Variation	t _{PWV}	21.1	23.1	19.1	23.4	ns	Electrical Input Signal according to
	Average Pulse Width Distortion	t _{APWD}	-0.5	0.5	-2.0	0.5	ns	MOST Specification of Physical Layer Rev. 1.0

Based on this table, the MOST System may be considered by two aspects:

a) In order to meet the MOST SPL Rev 1.0 at SP2 the t_{PWV} and t_{apwd} at SP1 have to be longer than described in the MOST SPL Rev. 1.0. This can be achived e.g. by using OS8104 as MOST transceiver chip.

b) If the MOST SPL Rev. 1.0 is met regarding t_{PWV} and t_{apwd} at SP1, then the output signal SP2 is systematically shortened. Within a MOST System, this characteristic can be compensated by the optical receiver which detects the signal at SP3. For this compensation, the optical receiver has to be specified in a range which is smaller than the range described in the MOST SPL Rev. 1.0. For a detailed evaluation of system behavior, see paper "OS8300 Revision J behavior on SP2 (optical output signal)" from Oasis SiliconSystems.



DC Characteristics

Parameter	Symbol	Min	Тур	Max	Unit
Low Level Input Voltage	V _{IL}	-0.3	-	0.8	V
High Level Input Voltage	V _{IH}	2.0	-	V _{CC} + 0.3	V
Input Leakage Current	IL I	-	-	+/- 20	μA
$(V_{CC}=5.0V, V_{I}=0.0V \text{ or } V_{I}=5.0V)$					
Input Capacitance	CI	-	-	7	pF
Input Resistance	R	100	-	-	kOhm
Supply Current (R _{ext} = 15 kOhm) ON state,	I _{cc}	-	25	35	mA
biphase coded data, see Note 3					
Supply Current (R _{ext} = 15 kOhm) OFF state,	I _{LP2}	-	-	1	mA
see Note 4					

Note 3: The current through the LED and therefore the optical output power and overall power consumption depends on the settings of R_{ext} . The nominal value for R_{ext} is 15K. With R_{ext} =30K the optical output power is about –3dB of the nominal value. Typical behaviour see Fiure below. Important: The external resistor of R_{ext} must be within the range of 13.5K to 33K. For values of R_{ext} out of this range functionality may not be given over the whole temperature range and the device lifetime. Using values below 13K for R_{ext} can damage the transmitter.

Note 4: The transmitter jumps to low power mode after TX DATA is low for max. 18µs If the transmitter is in low power mode it is switched ON 5μ s (max.) after TX DATA starts toggling.

AC Electrical Characteristics

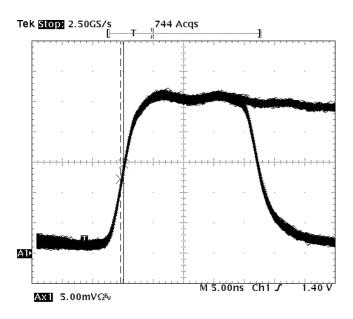
Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
Power Supply	25 MHz Power Supply	PSRR	-	30	-	dB
Rejection Ratio	Noise					
Power Up Time	Zero → MOST Data	T _{PU}	1.0	2.5	5.0	μs
Power Down Time	MOST Data → Zero	T _{PD}	-	-	18.0	μs
Input Rise Time		t _{TLH}	-	-	5	ns
Input Fall Time		t _{THL}	-	-	5	ns



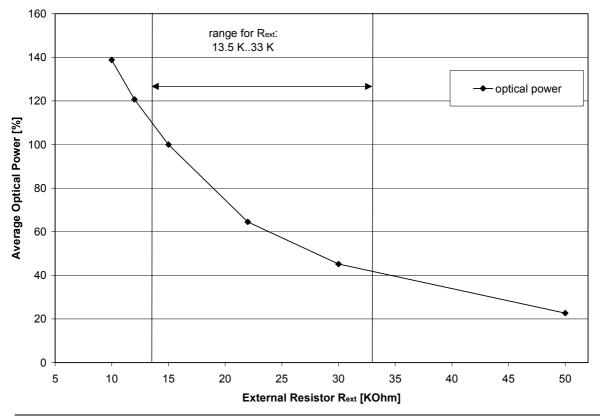


Typical Output Signal

Measured with fast optical receiver (Graviton SPD-1) with 15 kOhm external resistor and 22.579 Mbit/s MOST Data at T_A =25°C.



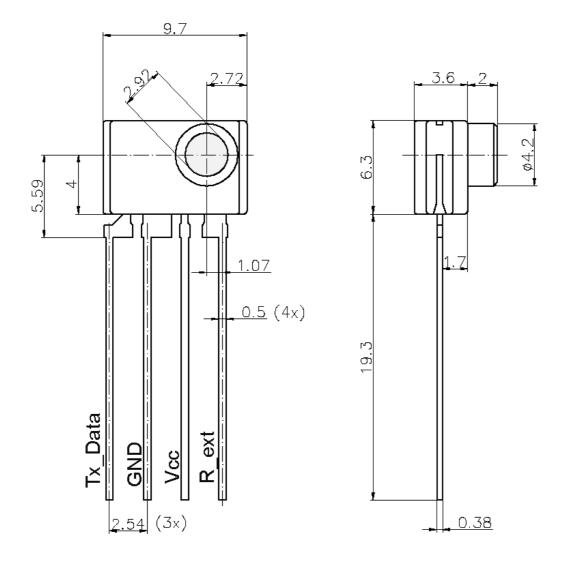
Typical Dependency of Average Output Power P_{opt} on external Resistor R_{ext} (22.5 MBit MOST Data/ V_{CC} =5 V / T_A=25°C)







Mechanical Design MIT3 02: CAI package (cavity as interface)



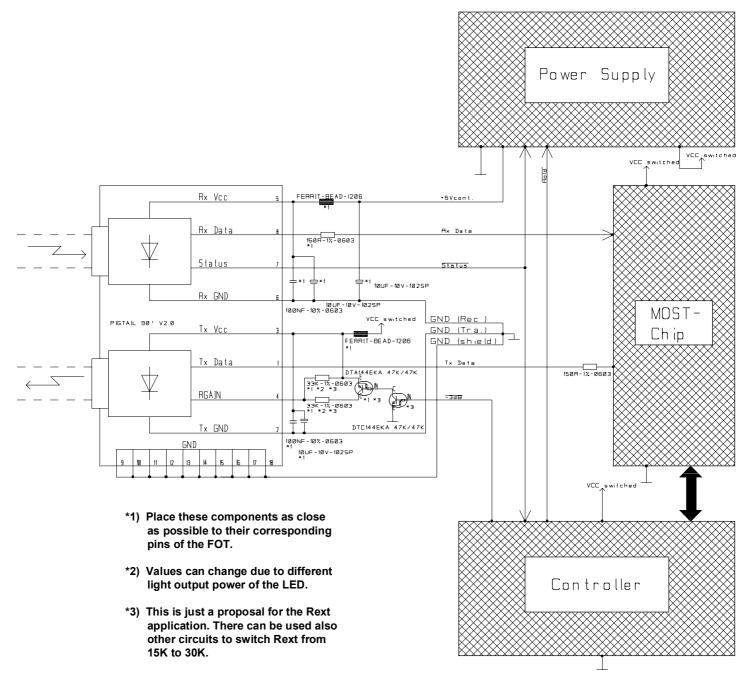
Lot number, production week, component type are given on CAI backside by laser marking (for details see marking specification).



SPF MIT3 02



Application Circuit:



Design & Layout rules:

- The 100nF bypass capacitors of the FOTs must be located as close as possible between the pins Vcc and GND of the FOTs. Use ceramic caps and tantalum caps with low ESR.
- Also the inductor/ferrite bead (receiver) and the -3dB control circuit (transmitter) must be placed as close as possible to the FOTs. We prefer ferrite beads (e.g. type 74279214 Würth Elektronik) since the d.c. resistance is very low. If other inductors are used the d.c. resistor should be less than 3Ohm.
- For EMC a ferrite bead should be connected to the power supply close to the transmitter and the



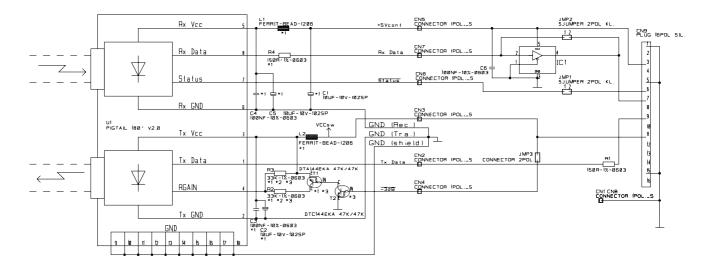


receiver. Do not use only one ferrite bead together for receiver and transmitter!

- For the ground connection a ground plane is recommended (Y-structure). That means the ground planes of the transmitter, the receiver and the shielding must be separated. The three ground planes should be connected together behind the bypass capacitors (refer to the PCB design below). This ground signal should be connected directly to the ground plane of the MOST controller (e.g. OS8104) and the power supply on the top layer and/or bottom layer and ground layer as it is indicated in the example below.
- If a multi layer design is used the ground layer must have the same ground separation like shown for the top layer!
- A serial resistor in the Rx/Tx data line will also reduce EMC problems. For Rx the resistor must be placed near the receiver for Tx the resistor must be placed near the MOST controller chip. The value depends from the distance between the FOTs and the MOST chip (< 5cm) and can be in the range of up to 150R. Higher values for the resistors will increase jitter and can therefore cause locking problems of the MOST PLL!
- The Rx/Tx signals should not be routed parallel over a long distance but may be embedded with ground copper, if possible.
- The GND pin and the pin of Rext (15K resistor) of the transmitter are used for heat dissipation. Therefore there should be a good connection to the PCB → no isolation gaps! Both pins should dip into a copper area (see layout example below).

Layout example:

The reference board from OASIS Silicon Systems follows the requirements above. The schematic is very similar to the example above, but does not include the connection to the power supply, the OS8104 or the microcontroller.



The examples below for top- and bottom layer is the layout of the reference design board and shows how the layout around the optical receiver and transmitter should look like. It is strongly recommended to follow this examples in your design to get best performance!

Note:

The buffer circuit (IC1), the connectors and jumpers in the middle to the right section of the schematic are only for use of the reference board and will not be necessary for your HW - design.

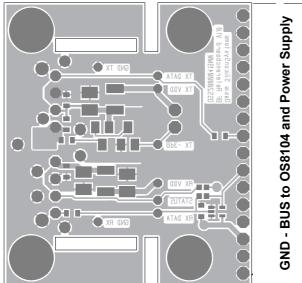




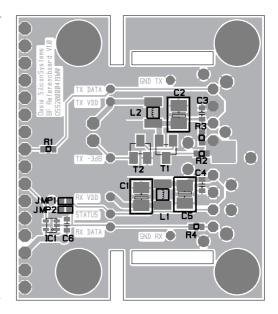
GND - BUS to OS8104 and Power Supply M1 ΜЗ \mathbb{C} C CN2 X DATA $(\neg$ JM ſ UI CN4 \bigcirc 1 5 C AX VDD $(\)$ CN7 \mathbb{C} М2 M4 Referenchoard CN9 520000419MW

Top Layer with 180° version of the pigtail:

Bottom Layer (seen from the top side of the PCB):



Bottom Layer: Bottom side / positions







Other items:

- The shown circuit for the –3dB attenuation is just a proposal. Also any other circuit which can double the value of R_{ext} is permitted.
- Due to the fact that the optical average level jumps if the power control signal (/-3dB) is toggled there can occur LOCK/coding errors at the following device for a short time. This is not very critical, since it does occur only in diagnosis mode. After a time of 10ms the device should lock again if the optical attenuation between the devices is not too high.
- The Rx and Tx signals can be measured by using standard probes (>1M/<10pF). However, if the signal quality is very bad and the LOCK signal of the MOST chip is flaky connecting a passive probe to the Rx signal can cause the MOST chip to lock better or worse to the signal. This is due to the capacitance of the analog probe which is usually in the range of 8..12pF and shifts the phase and PWD of the signal. In this case an active probe with a capacitance of less than 1pF is recommended.
- The reference test board which corresponds to the layout examples above is available at the Oasis Silicon System AG.



SPF MIT3 02

History of Design and Specification Status of MOST Transmitter:

Data Sheet Status	Bigfoot IC Revision	device marking	comments, cause of change, important differences to last Status
02-Dec-02	J	Date code MIT3 02	New release
15-Jan-03	J	date code, MIT3 02	 p. 2: Update of Note 2 p. 3: Section Pulse Width Variation (t_{PWV}) and Average Pulse Width Distortion (t_{APWD}) added



Notes:

